

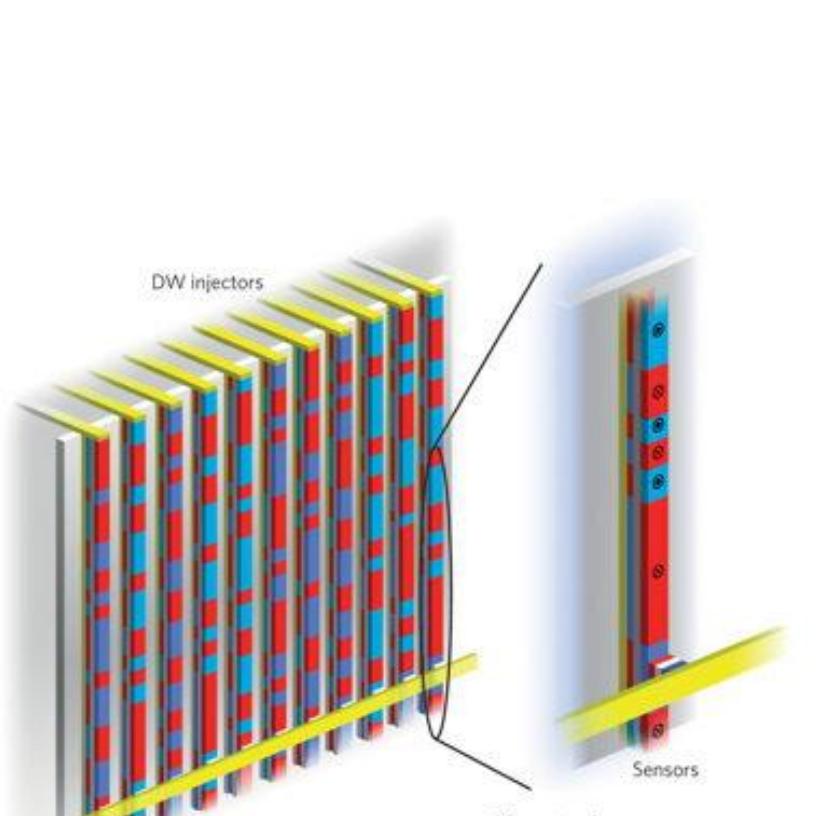
Domain-wall pinning at chemical notches in cylindrical nanowires

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Motivation

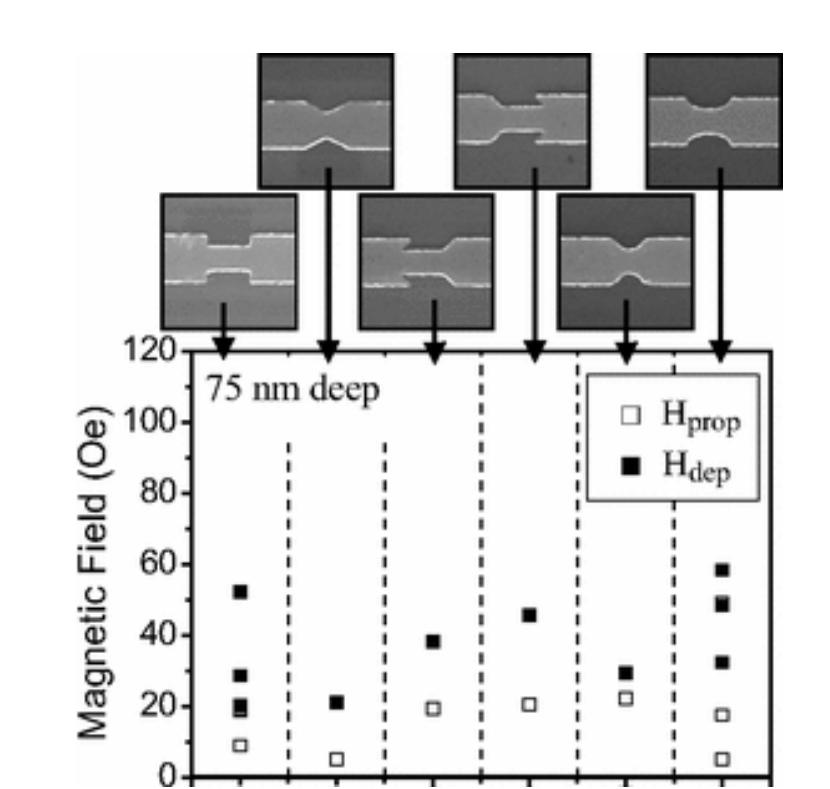
The movement of magnetic domain walls (DWs) using spin-polarized currents may be the base of next future magnetic storage technology.



Racetrack memory, suggested by Stuart Parkin (IBM): magnetic DWs are pinned in artificially created **geometrical notches** along the wires [1].

The depinning of a DW has an intrinsic **stochastic component**. The **Joule heating** associated to the spin-polarized currents is more important than thought previously [2,3].

Our proposal: introduce **changes in composition** along **cylindrical nanowires** (chemical notches) to use them as local pinning sites.



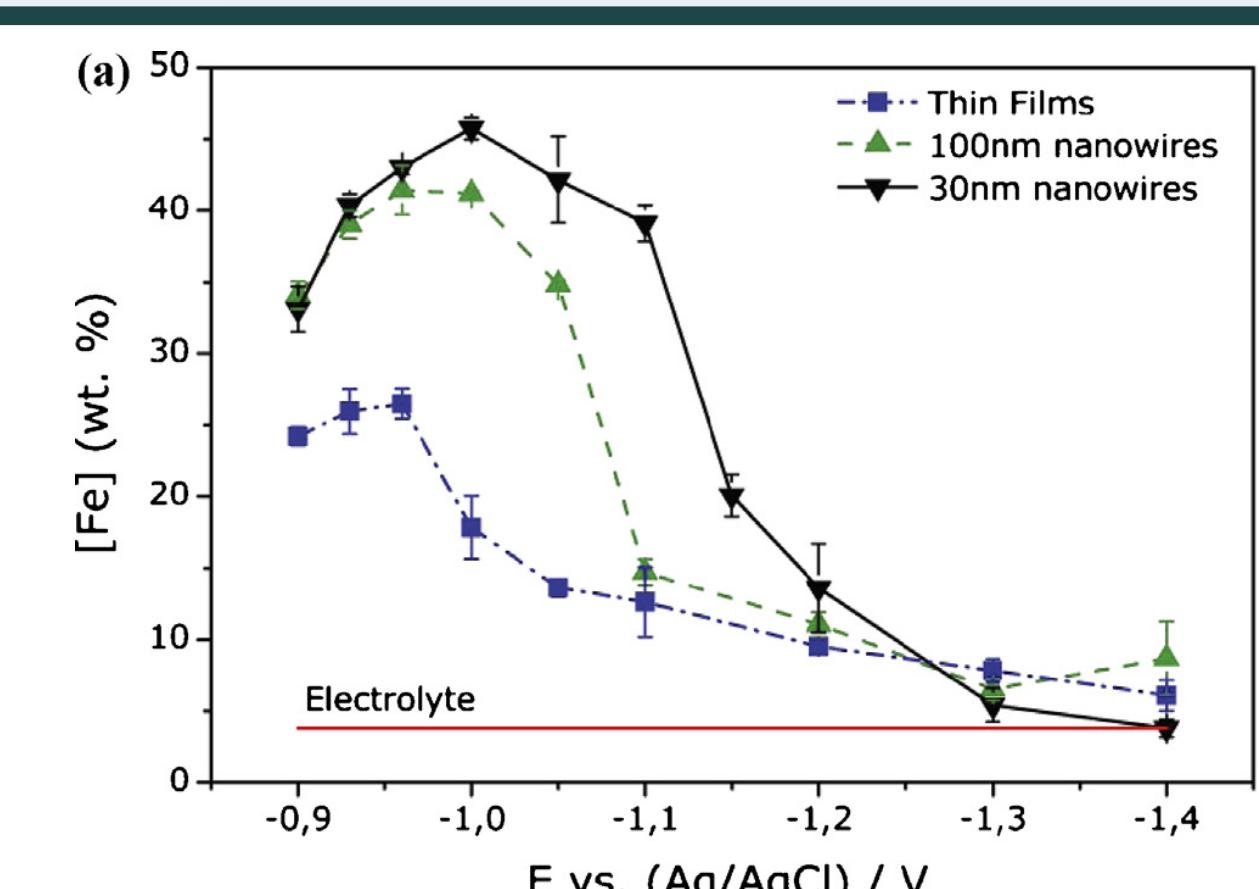
Experimental

Growth conditions:

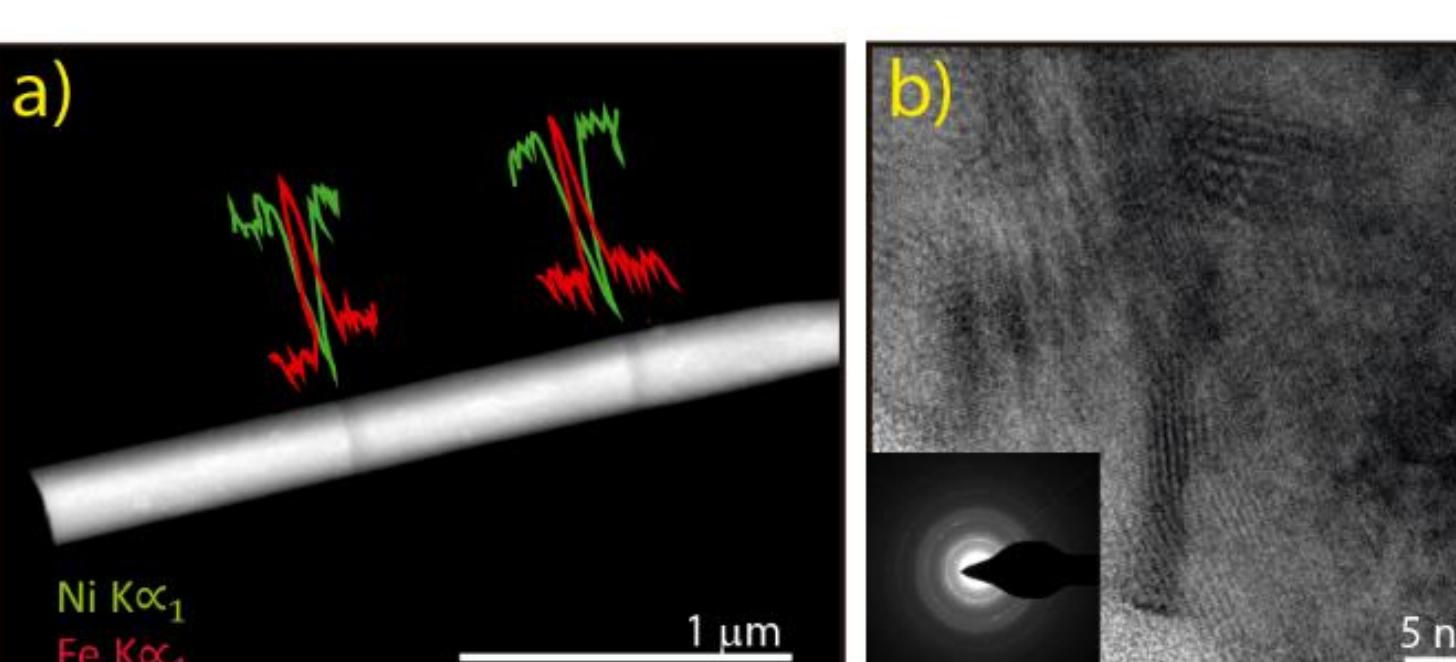
Potentiostatic electrodeposition

Alumina templates: 200nm diameter

Pulsed electrodeposition: $V=-1.5\text{ V}$ 3.5s-15s
 $V=-1\text{ V}$ 15s



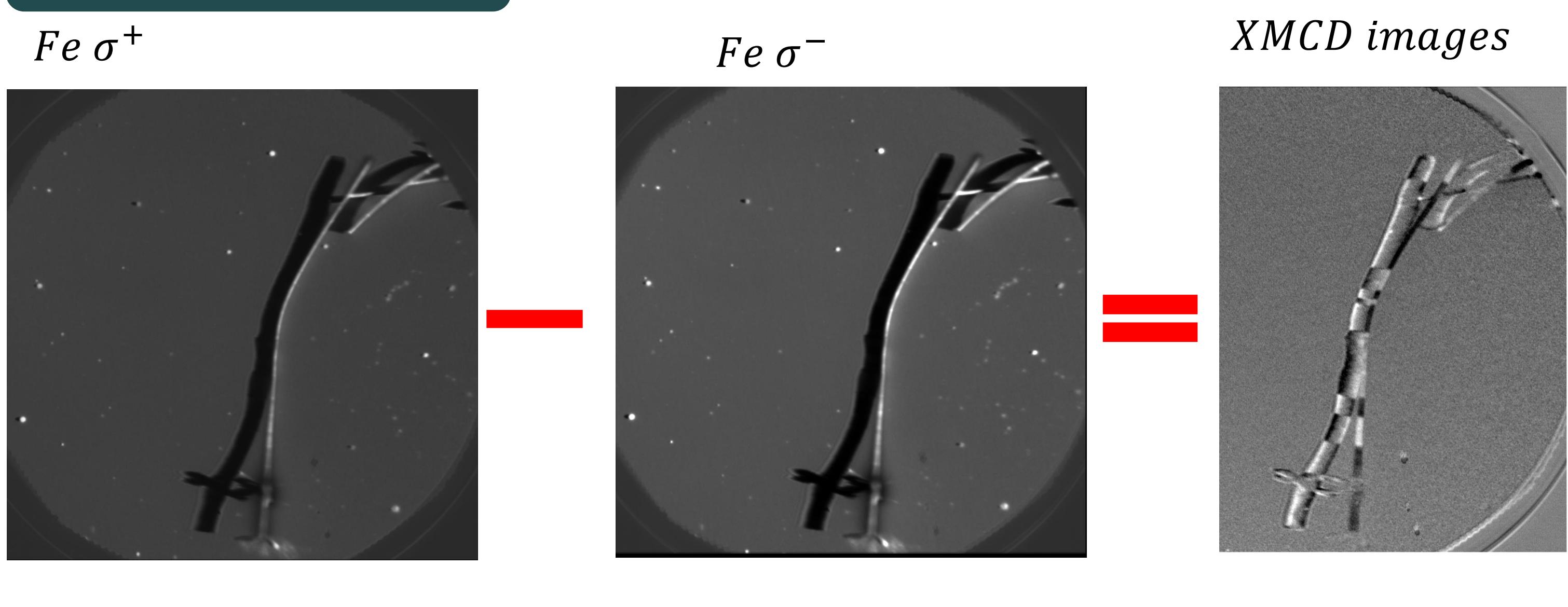
TEM



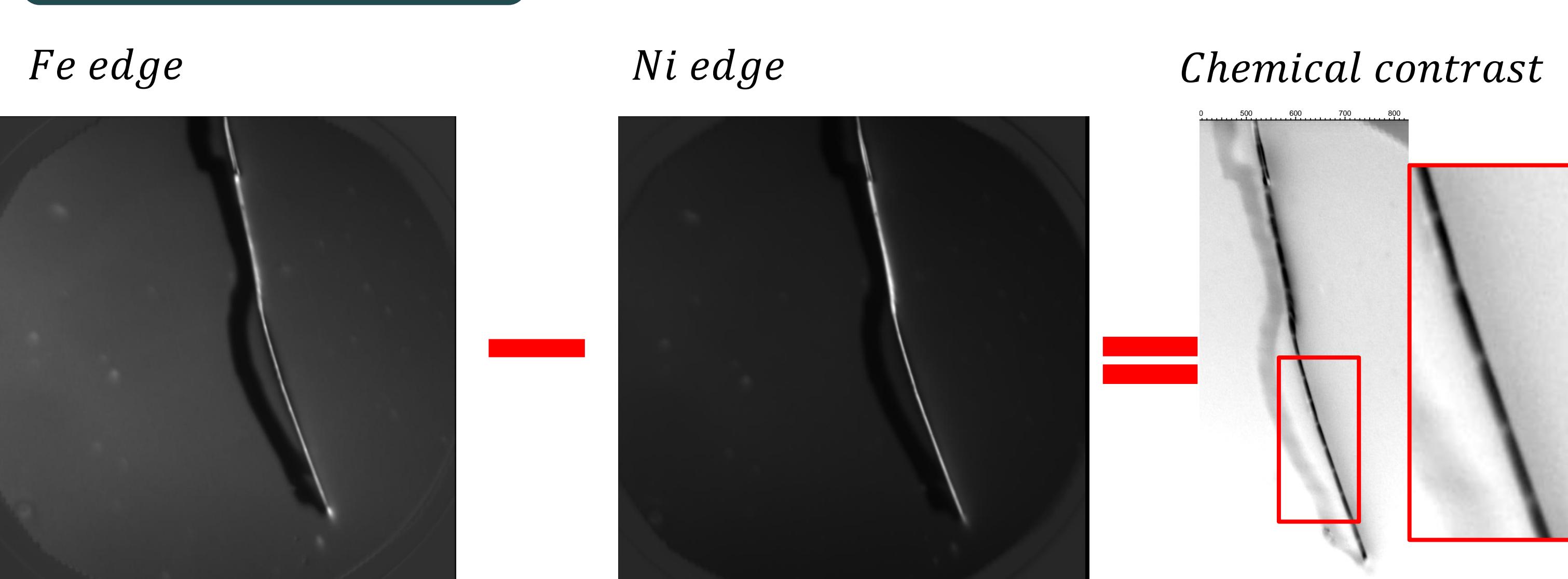
Dark and light segments in the nanowire corresponds to Ni-rich and Fe-rich areas (chemical notches) respectively.

Chemical notches are 20 nm in length and are periodically distributed

Magnetic contrast

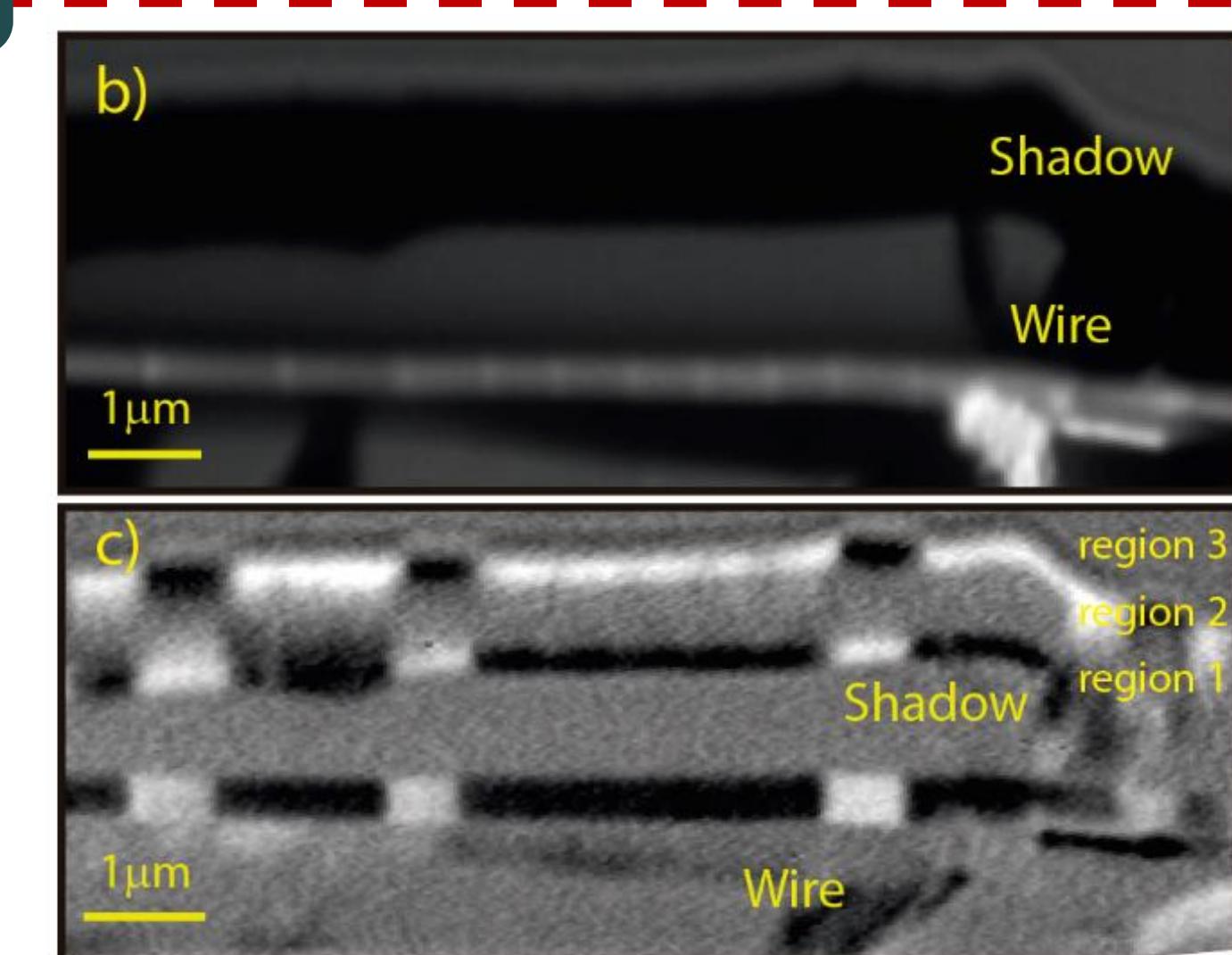
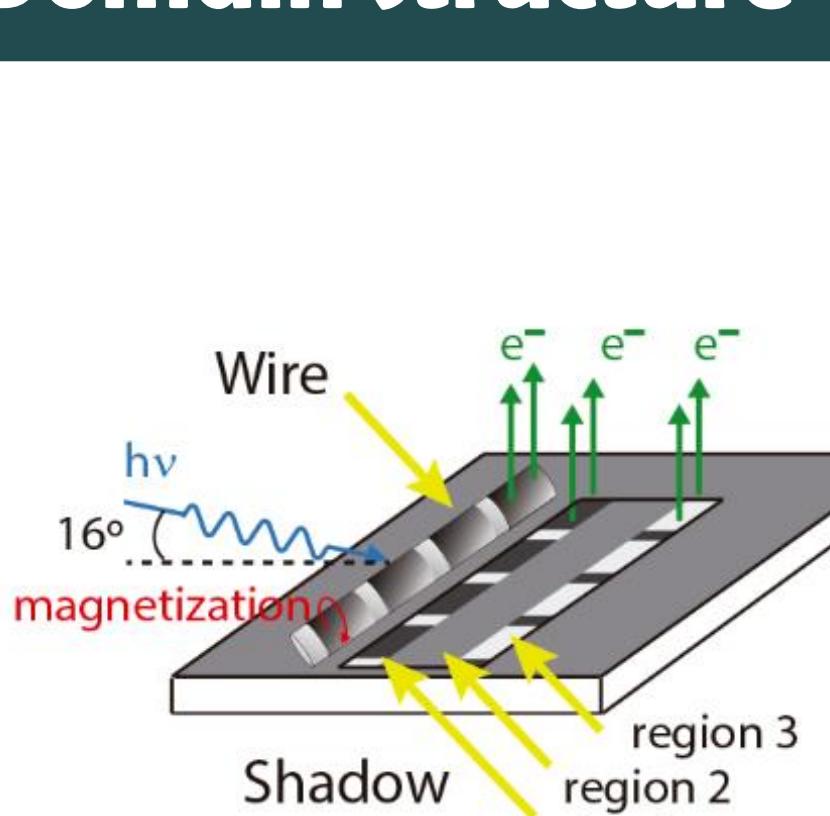


Chemical contrast

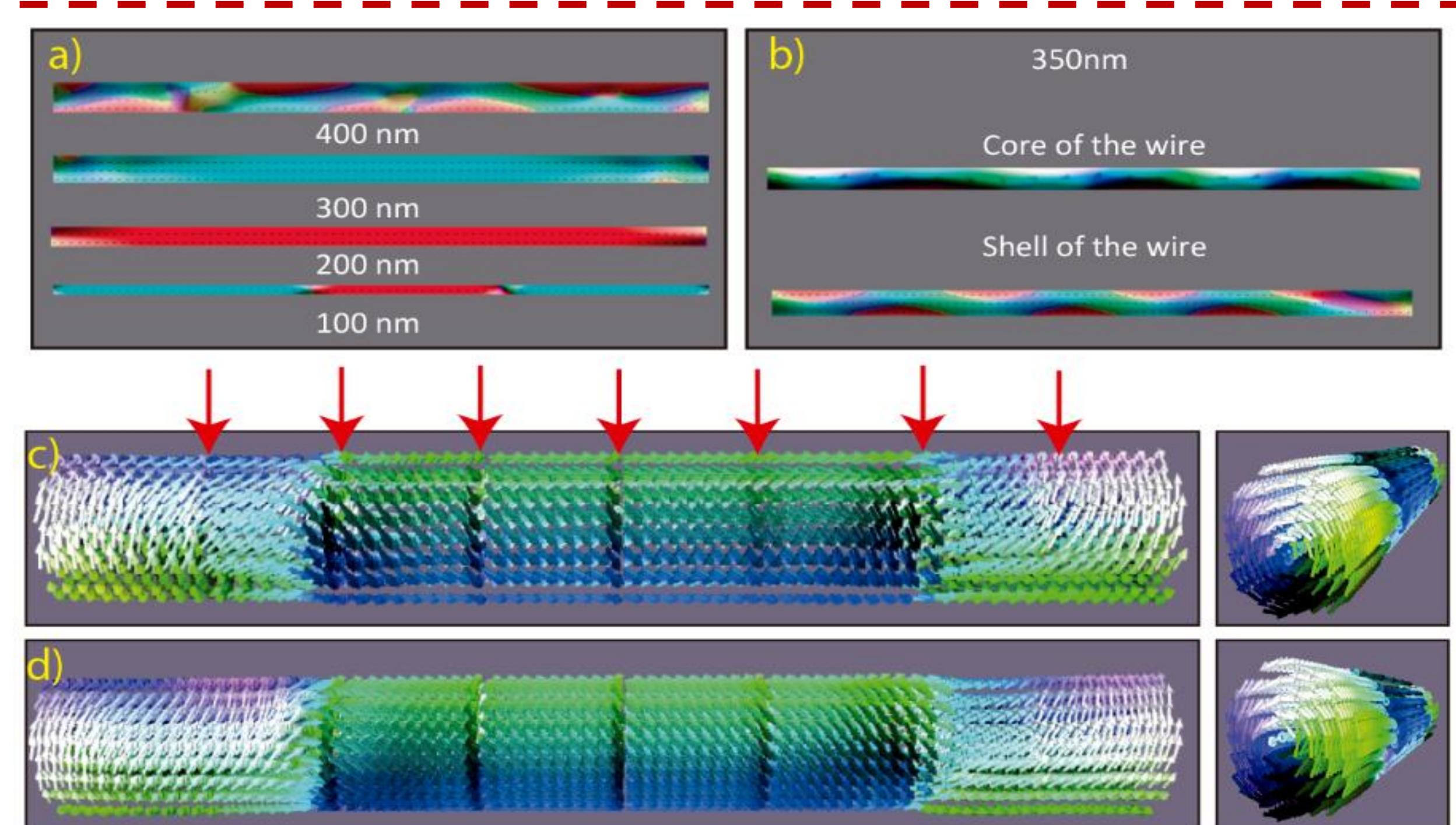


Domain structure

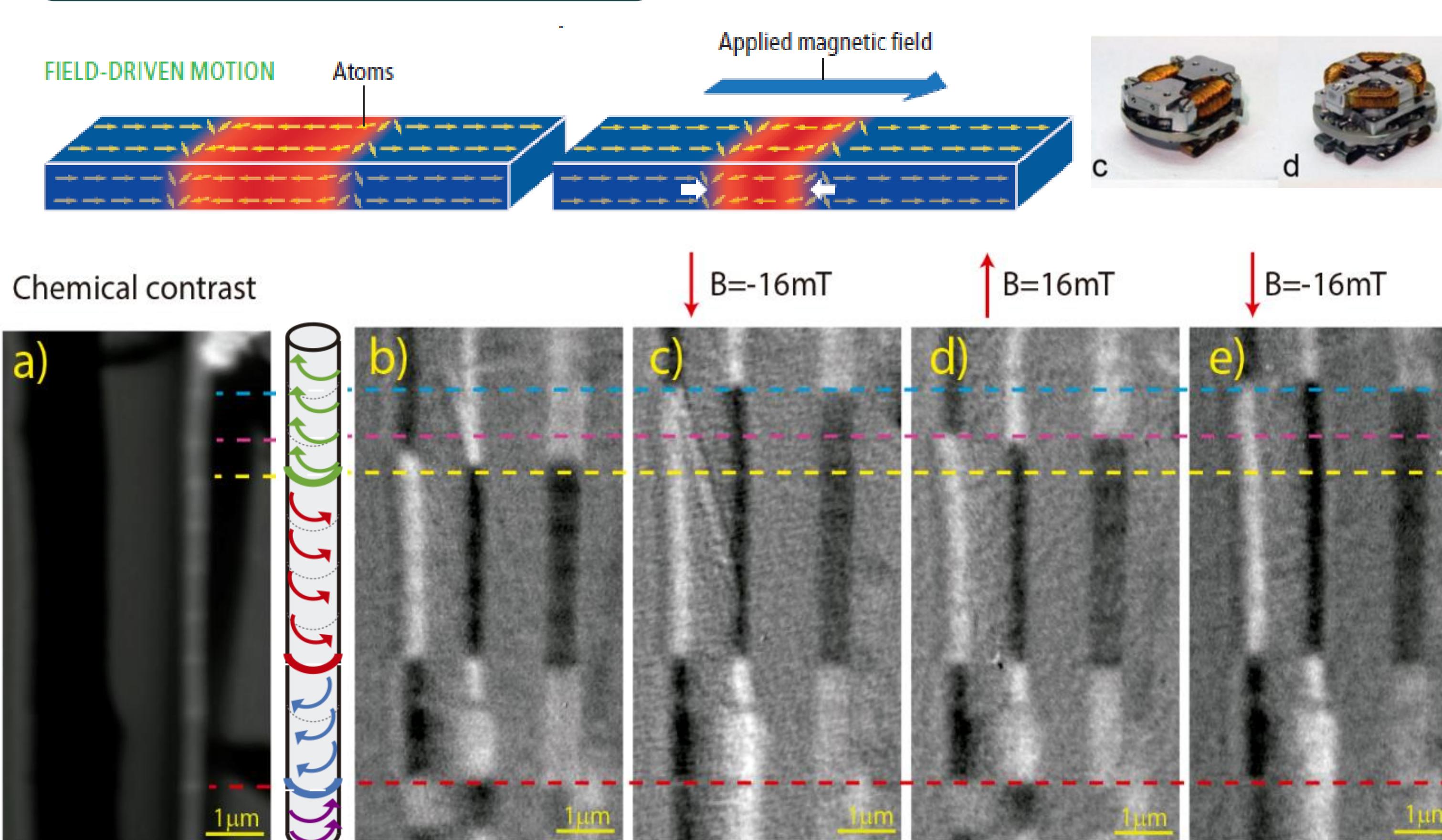
Experimental



Chemical Simulation



Domain Wall motion



Conclusions

Permalloy nanowires with chemical notches have **two different magnetic configurations**: Core/shell for lower diameters and helical configuration for higher diameters.

95% of domain walls are pinned in notches

The **depinning field** is **the same** for all studied notches

References

- [1] S. S. P. Parkin, et al. Science, 320:194, 2008.
- [2] Johanna Akerman, et al. Phys. Rev. B, 82:064426, 2010.
- [3] M. Munoz and J. L. Prieto. Nat. Commun. 171:63, 2016.
- [4] M. Foerster, et al. Ultramicroscopy., 96:082110, 2010

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